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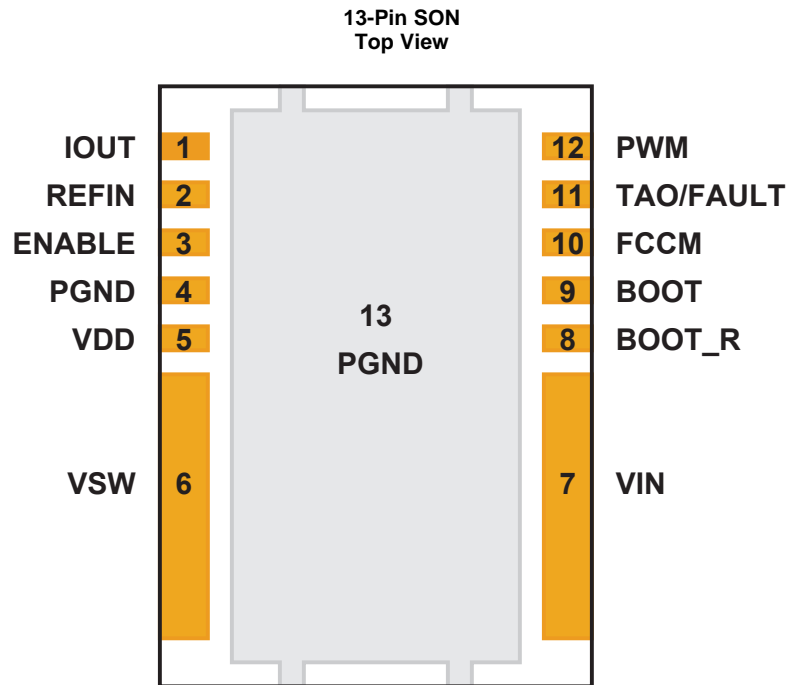
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4 Revision History

Changes from Revision A (July 2014) to Revision B	Page
• Updated the CSD95378B parts in the Application Schematic	5
• Added the Receiving Notification of Documentation Updates and Community Resources sections in Device and Documentation Support	6

Changes from Original (April 2014) to Revision A	Page
• Updated the controller IC in the Application Schematic to the TPS40428	5

5 Pin Configuration and Functions



Pin Functions

PIN		DESCRIPTION
NAME	NO.	
BOOT	9	Bootstrap capacitor connection. Connect a minimum of 0.1-μF, 16-V, X7R ceramic capacitor from BOOT to BOOT_R pins. The bootstrap capacitor provides the charge to turn on the control FET. The bootstrap diode is integrated.
BOOT_R	8	Return path for HS gate driver, connected to V _{SW} internally.
ENABLE	3	Enables device operation. If ENABLE = logic HIGH, turns on device. If ENABLE = logic LOW, the device is turned off and both MOSFET gates are actively pulled low. An internal 100-kΩ pulldown resistor will pull the ENABLE pin LOW if left floating.
FCCM	10	This pin enables the Diode Emulation function. When this pin is held LOW, Diode Emulation Mode is enabled for sync FET. When FCCM is HIGH, the device is operated in Forced Continuous Conduction Mode. An internal 5-μA current source will pull the FCCM pin to 3.3 V if left floating.
IOUT	1	Output of current sensing amplifier. V(IOUT) – V(REFIN) is proportional to the phase current.
P _{GND}	4	Power ground, connected directly to pin 13.
P _{GND}	13	Power ground.
PWM	12	Pulse width modulated tri-state input from external controller. Logic LOW sets control FET gate low and sync FET gate high. Logic HIGH sets control FET gate high and sync FET gate low. Open or Hi-Z sets both MOSFET gates low if greater than the tri-state shutdown hold-off time (t _{3HT}).
REFIN	2	External reference voltage input for current sensing amplifier.
TAO/ FAULT	11	Temperature analog output. Reports a voltage proportional to the die temperature. An ORing diode is integrated in the IC. When used in multiphase application, a single wire can be used to connect the TAO pins of all the ICs. Only the highest temperature will be reported. TAO will be pulled up to 3.3 V if thermal shutdown occurs. TAO should be bypassed to P _{GND} with a 1-nF, 16-V, X7R ceramic capacitor.
V _{DD}	5	Supply voltage to gate driver and internal circuitry.
V _{IN}	7	Input voltage pin. Connect input capacitors close to this pin.
V _{SW}	6	Phase node connecting the HS MOSFET source and LS MOSFET drain - pin connection to the output inductor.

6 Specifications

6.1 Absolute Maximum Ratings

 $T_A = 25^{\circ}\text{C}$ (unless otherwise noted)⁽¹⁾

	MIN	MAX	UNIT
V_{IN} to P_{GND}	−0.3	25	V
V_{IN} to V_{SW}	−0.3	25	V
V_{IN} to V_{SW} (10 ns)	−7	27	V
V_{SW} to P_{GND}	−0.3	20	V
V_{SW} to P_{GND} (10 ns)	−7	23	V
V_{DD} to P_{GND}	−0.3	7	V
ENABLE, PWM, FCCM, TAO, IOUT, REFIN to P_{GND}	−0.3	$V_{DD} + 0.3\text{ V}$	V
BOOT to BOOT_R ⁽²⁾	−0.3	$V_{DD} + 0.3\text{ V}$	V
Power dissipation, P_D		12	W
Operating junction temperature, T_J	−55	150	$^{\circ}\text{C}$
Storage temperature, T_{stg}	−55	150	$^{\circ}\text{C}$

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the *Recommended Operating Conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) Should not exceed 7 V.

6.2 ESD Ratings

		MIN	MAX	UNIT	
V _(ESD)	Electrostatic discharge	Human-body model (HBM)	−2000	2000	V
		Charged-device model (CDM)	−500	500	

6.3 Recommended Operating Conditions

 $T_A = 25^{\circ}\text{C}$ (unless otherwise noted)

	MIN	MAX	UNIT
V_{DD} Gate drive voltage	4.5	5.5	V
V_{IN} Input supply voltage ⁽¹⁾		16	V
V_{OUT} Output voltage		5.5	V
I_{OUT} Continuous output current	$V_{IN} = 12\text{ V}$, $V_{DD} = 5\text{ V}$, $V_{OUT} = 1.2\text{ V}$, $f_{SW} = 500\text{ kHz}$, $L_{OUT} = 0.225\text{ }\mu\text{H}$ ⁽²⁾		60
I_{OUT-PK} Peak output current ⁽³⁾			90
f_{SW} Switching frequency	$C_{BST} = 0.1\text{ }\mu\text{F}$ (min)	1250	kHz
On-time duty cycle	$f_{SW} = 1\text{ MHz}$	85%	
Minimum PWM on time	40		ns
Operating temperature	−40	125	$^{\circ}\text{C}$

- (1) Operating at high V_{IN} can create excessive AC voltage overshoots on the switch node (V_{SW}) during MOSFET switching transients. For reliable operation, the switch node (V_{SW}) to ground voltage must remain at or below the *Absolute Maximum Ratings*.
- (2) Measurement made with six 10- μF (TDK C3216X5R1C106KT or equivalent) ceramic capacitors placed across V_{IN} to P_{GND} pins.
- (3) System conditions as defined in Note 1. Peak output current is applied for $t_p = 50\text{ }\mu\text{s}$.

6.4 Thermal Information

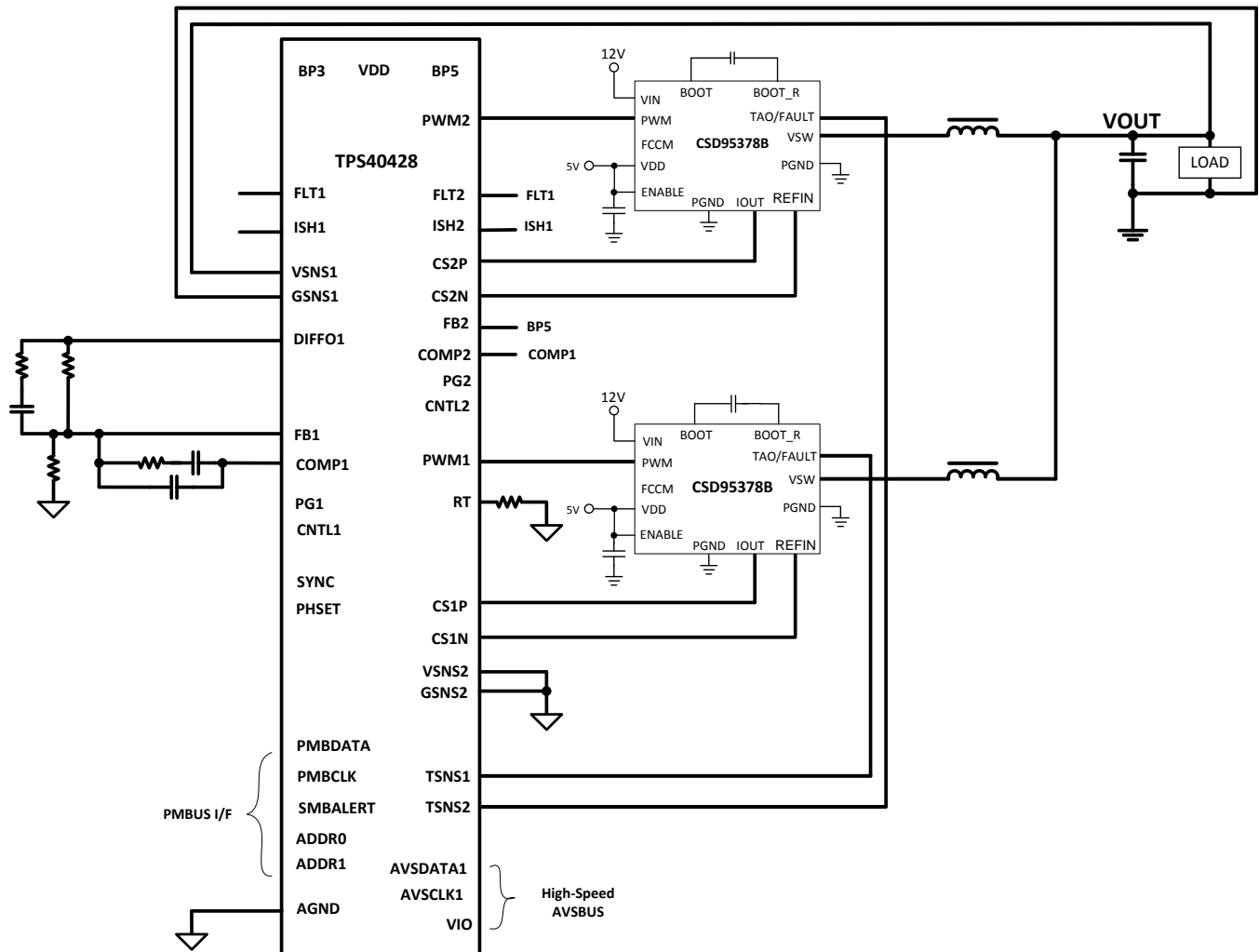
 $T_A = 25^{\circ}\text{C}$ (unless otherwise noted)

THERMAL METRIC	MIN	TYP	MAX	UNIT
$R_{\theta JC}$ Junction-to-case (top-of-package) thermal resistance ⁽¹⁾			15	$^{\circ}\text{C/W}$
$R_{\theta JB}$ Junction-to-board thermal resistance ⁽²⁾			1.5	

- (1) $R_{\theta JC}$ is determined with the device mounted on a 1-in² (6.45 -cm²), 2-oz (0.071-mm) thick Cu pad on a 1.5-in × 1.5-in, 0.06-in (1.52-mm) thick FR4 board.
- (2) $R_{\theta JB}$ value based on hottest board temperature within 1 mm of the package.

7 Application Schematic

7.1 Typical Application



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8 Device and Documentation Support

8.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

8.2 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

TI E2E™ Online Community *TI's Engineer-to-Engineer (E2E) Community*. Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

8.3 Trademarks

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8.4 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

8.5 Glossary

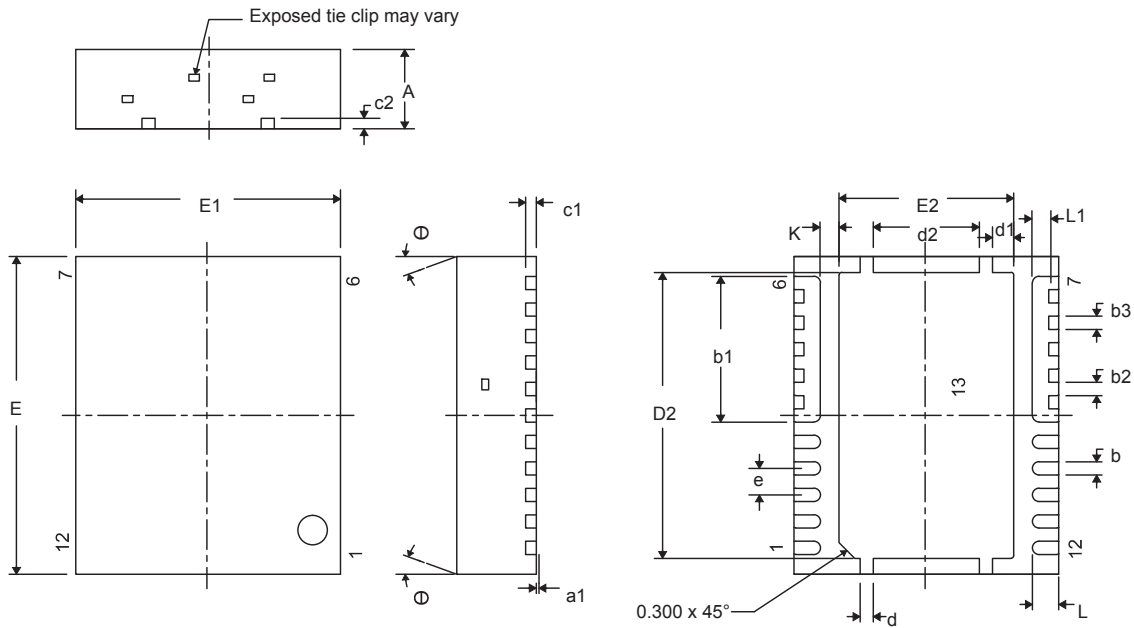
[SLYZ022](#) — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

9 Mechanical, Packaging, and Orderable Information

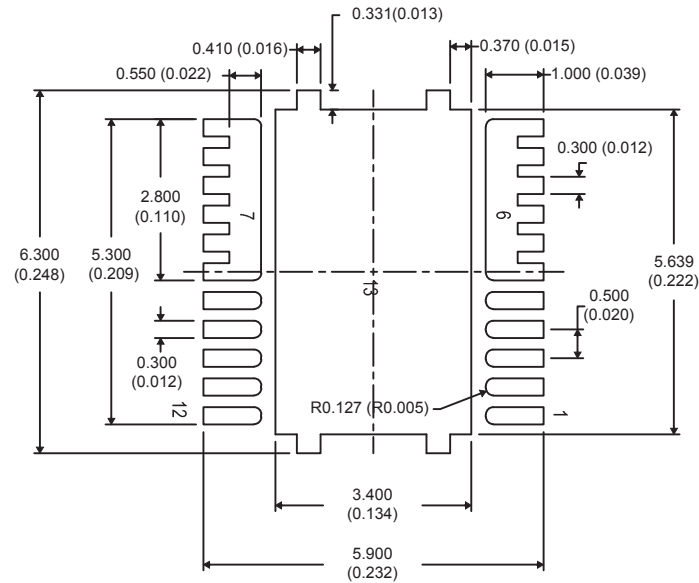
The following pages include mechanical packaging and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

9.1 Mechanical Drawing



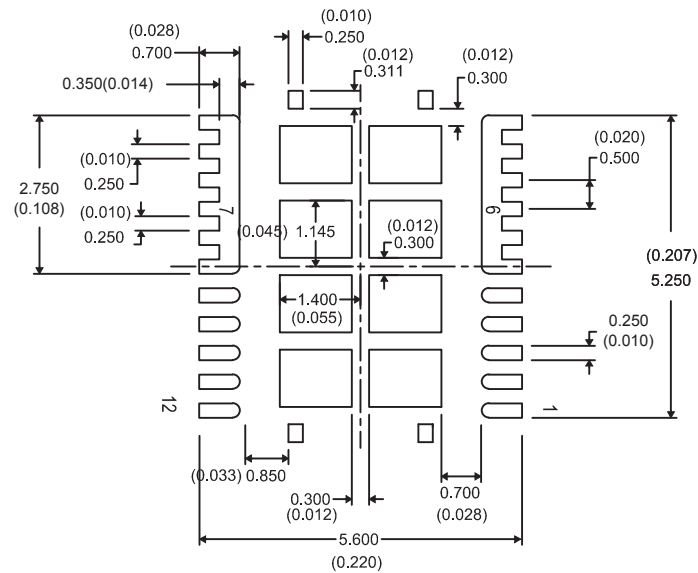
DIM	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	1.400	1.450	1.500	0.057	0.059	0.061
a1	0.000	0.000	0.050	0.000	0.000	0.002
b	0.200	0.250	0.320	0.008	0.010	0.013
b1	2.750 TYP			0.108 TYP		
b2	0.200	0.250	0.320	0.008	0.010	0.013
b3	0.250 TYP			0.010 TYP		
c1	0.150	0.200	0.250	0.006	0.008	0.010
c2	0.200	0.250	0.300	0.008	0.010	0.012
D2	5.300	5.400	5.500	0.209	0.213	0.217
d	0.200	0.250	0.300	0.008	0.010	0.012
d1	0.350	0.400	0.450	0.014	0.016	0.018
d2	1.900	2.000	2.100	0.075	0.079	0.083
E	5.900	6.000	6.100	0.232	0.236	0.240
E1	4.900	5.000	5.100	0.193	0.197	0.201
E2	3.200	3.300	3.400	0.126	0.130	0.134
e	0.500 TYP			0.020 TYP		
K	0.350 TYP			0.014 TYP		
L	0.400	0.500	0.600	0.016	0.020	0.024
L1	0.210	0.310	0.410	0.008	0.012	0.016
θ	0.00	—	—	0.00	—	—

9.2 Recommended PCB Land Pattern



1. Dimensions are in mm (in).

9.3 Recommended Stencil Opening



1. Dimensions are in mm (in).
2. Stencil thickness is 100 μm .

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
CSD95378BQ5M	Active	Production	LSON-CLIP (DQP) 12	2500 LARGE T&R	ROHS Exempt	NIPDAU SN	Level-2-260C-1 YEAR	-55 to 150	95378BM
CSD95378BQ5M.A	Active	Production	LSON-CLIP (DQP) 12	2500 LARGE T&R	ROHS Exempt	NIPDAU	Level-2-260C-1 YEAR	-55 to 150	95378BM
CSD95378BQ5M.B	Active	Production	LSON-CLIP (DQP) 12	2500 LARGE T&R	ROHS Exempt	NIPDAU	Level-2-260C-1 YEAR	-55 to 150	95378BM
CSD95378BQ5MG4.A	Active	Production	LSON-CLIP (DQP) 12	2500 LARGE T&R	ROHS Exempt	NIPDAU	Level-2-260C-1 YEAR	-55 to 150	95378BM
CSD95378BQ5MG4.B	Active	Production	LSON-CLIP (DQP) 12	2500 LARGE T&R	ROHS Exempt	NIPDAU	Level-2-260C-1 YEAR	-55 to 150	95378BM
CSD95378BQ5MT	Active	Production	LSON-CLIP (DQP) 12	250 SMALL T&R	ROHS Exempt	NIPDAU	Level-2-260C-1 YEAR	-55 to 150	95378BM
CSD95378BQ5MT.A	Active	Production	LSON-CLIP (DQP) 12	250 SMALL T&R	ROHS Exempt	NIPDAU	Level-2-260C-1 YEAR	-55 to 150	95378BM
CSD95378BQ5MT.B	Active	Production	LSON-CLIP (DQP) 12	250 SMALL T&R	ROHS Exempt	NIPDAU	Level-2-260C-1 YEAR	-55 to 150	95378BM

(1) **Status:** For more details on status, see our [product life cycle](#).

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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TAPE AND REEL INFORMATION



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CSD95378BQ5M	LSON-CLIP	DQP	12	2500	330.0	12.4	5.3	6.3	1.8	8.0	12.0	Q1
CSD95378BQ5MT	LSON-CLIP	DQP	12	250	180.0	12.4	5.3	6.3	1.8	8.0	12.0	Q1

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CSD95378BQ5M	LSON-CLIP	DQP	12	2500	346.0	346.0	33.0
CSD95378BQ5MT	LSON-CLIP	DQP	12	250	210.0	185.0	35.0

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